



74LV14A

HEX INVERTERS WITH SCHMITT TRIGGER INPUTS

Description

The 74LV14A provides provides six independent Schmitt Trigger input inverters with standard push-pull outputs. The device is designed for operation with a power supply range of 2.0V to 5.5V.

The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using l_{OFF} . The l_{OFF} circuitry disables the output preventing damaging current backflow when the device is powered down.

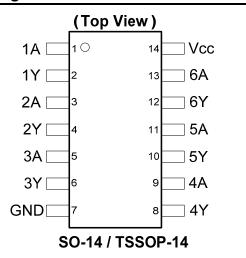
The gates perform the Boolean function:

 $Y = \overline{A}$

Features

- Wide Supply Voltage Range from 2.0V to 5.5V
- Sinks or sources 12mA at V_{CC} = 4.5V
- CMOS low power consumption
- I_{OFF} Supports Partial -Power Down Operation
- Inputs or Outputs accept up to 5.5V
- Inputs can be driven by 3.3V or 5V allowing for voltage translation applications.
- Schmitt Trigger Action at All Inputs
- ESD Protection Tested per JESD 22
 - Exceeds 200-V Machine Model (A115)
 - Exceeds 2000-V Human Body Model (A114)
 - Exceeds 1000-V Charged Device Model (C101)
- Latch-Up Exceeds 100mA per JESD 78, Class I
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Pin Assignments



Applications

- General Purpose Logic
- Power Down Signal Isolation
- Wide array of products such as:
 - PCs, networking, notebooks, ultrabooks, netbooks
 - Computer peripherals, hard drives, CD/DVD ROM
 - TV, DVD, DVR, set top box

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

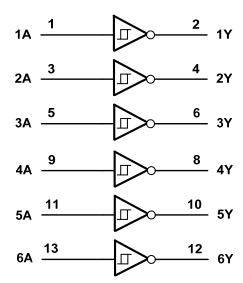
Click here for ordering information, located at the end of datasheet



Pin Descriptions

Pin Number Pin Name Description Data Input 2 1Y Data Output 3 2A Data Input 4 2Y Data Output 5 3A Data Input 6 3Y Data Output 7 GND Ground 8 4Y Data Output 9 4A Data Input 5Y 10 Data Output 11 5A Data Input 6Y 12 Data Output 13 6A Data Input 14 VCC Supply Voltage

Logic Diagram



Function Table

Input	Output
Α	Y
Н	L
L	Н

Absolute Maximum Ratings (Note 4) (@T_A = +25°C, unless otherwise specified.)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
ESD MM	Machine Model ESD Protection	200	V
V_{CC}	Supply Voltage Range	-0.5 to +7.0	V
VI	Input Voltage Range note 4	-0.5 to +7.0	V
I _{IK}	Input Clamp Current V _I < 0V	-20	mA
lok	Output Clamp Current Vo<-0V	-50	mA
I _O	Continuous Output Current - 0.5V < V _O V _{CC} + 0.5V	±25	mA
Icc	Continuous Current Through V _{CC}	50	mA
I _{GND}	Continuous Current Through GND	-50	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C
P _{TOT}	Total Power Dissipation	500	mW

Note:

4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.



Recommended Operating Conditions (Note 5) (@TA = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	Supply Voltage	_	2.0	5.5	V
VI	Input Voltage	_	0	5.5	V
Vo	Output Voltage	_	0	Vcc	V
I _{OH} High-Level Output Current	2.0V	_	-50	mA	
	High-Level Output Current	2.3V to 2.7V	_	-2	μΑ
		3.0V to 3.6V	_	-6	mA
		4.5V to 5.5V	_	-12	mA
		2.0V	_	50	μA
	Low Lovel Output Current	2.3V to 2.7V	_	2	mA
l _{OL}	Low-Level Output Current	3.0V to 3.6V	_	6	mA
		4.5V to 5.5V	_	12	mA
TA	Operating Free-Air Temperature	_	-40	+125	°C

Note:

5. Unused inputs should be held at V_{CC} or Ground.

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Comple al	Damamatan	Took Conditions	.,	T _A = -40°0	C to +85°C	T _A = -40°C	to +125°C	l losia
Symbol	Parameter	Test Conditions	Vcc	Min	Max	Min	Max	Unit
Booitive Coing	_	2.5 V	1	1.75	1	1.75		
V_{T^+}	Positive Going Threshold	_	3.3 V	1.31	2.31	1.31	2.31	V
	THICSHOIL	_	5.0 V	1.95	3.5	1.95	3.5	
	Namativa Caina	_	2.5 V	0.75	1.5	0.75	1.5	
V_{T-}	Negative Going Threshold	_	3.3 V	0.99	2.07	0.99	2.07	_
	THESHOL	_	5.0 V	1.5	3.05	1.5	3.05	
	V _H Hysteresis (V _{T+-} V _{T-)}	_	2.5 V	0.25	1	0.25	1	
V_{H}		_	3.3 V	0.33	1.32	0.33	1.32	V
		_	5.0 V	0.5	2	0.5	2	
		I _{OH} = -50μA	2.0V to 5.5V	V _{CC} -0.1	_	V _{CC} -0.1	_	V
V	High-Level	$I_{OH} = -2mA$	2.3V	2.0	_	2.0	_	
V_{OH}	Output Voltage	$I_{OH} = -6mA$	3.0V	2.48	_	2.48	_	\ \ \
		I _{OH} = -12mA	4.5V	3.8	_	3.8	_	
		I _{OL} = 50μA	2.0V to 5.5V	_	0.1	_	0.1	
	Low-Level	I _{OL} = 2mA	2.3V	_	0.4	_	0.4	V
V_{OL}	Output Voltage	I _{OL} = 6mA	3.0V	_	0.44	_	0.44	\ \ \
		I _{OL} = 12mA	4.5V	_	0.55	_	0.55	
loff	Power Down Leakage Current	V _I or V _O = 0 to 5.5V	0V	_	5	_	5	μΑ
I _I	Input Current	V _I = GND or 5.5V	0 to 5.5V	_	±1	_	±1	μΑ
Icc	Supply Current	$V_I = GND \text{ or } V_{CC}$ $I_O = 0$	5.5V	_	20	_	20	μΑ



Switching Characteristics

Complete Deservator		Test			T _A = +25°C		-40°C to +85°C		-40°C to +125°C		l lmi4
Symbol Parameter	Conditions V _{CC}	VCC	Min	Тур.	Max	Min	Max	Min	Max	Unit	
		Figure 4	2.5V ± 0.2V	_	10.2	19.7	1	22	1	22	
		Figure 1 $C_L = 15pF$	$3.3V \pm 0.3V$	_	7.3	12.8	1	15	1	15.9	ns
	Propagation	CL = 13pi	5.0V ± 0.5V	_	5.1	8.6	1	10	1	10	
t _{PD}	Delay A _N to Y _N	F: .	2.5V ± 0.2V	_	13.3	24	1	27	1	27	
	Figure 1 C _L = 50pF	$3.3V \pm 0.3V$	_	9.6	16.3	1	18.5	1	19.4	ns	
		5.0V ± 0.5V	_	6.7	10.6	1	12	1	12		

Operating Characteristics (@T_A = +25°C, unless otherwise specified.)

	Parameter	Test Conditions	V _{CC}	Тур	Unit
0	Power Dissipation	F= 10 MHz	3.3V	8.8	ړ
$C_{\sf pd}$	Capacitance per Gate	C _L =50pF	5.0V	9.6	pF

Noise Characteristics

 $V_{CC} = 3V$, $C_L = 50pF T_A = +25°C$

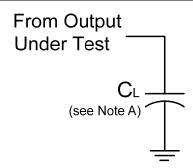
Symbol	Parameter	Min	Тур	Max	Unit
$V_{OL(p)}$	Quiet output, maximum dynamic V _{OL}	_	0.2	0.8	V
V _{OL(V)}	Quiet output, minimum dynamic V _{OL}	_	-0.1	-0.8	V
V _{OH(V)}	Quiet output, minimum dynamic V _{OH}	_	3.1	_	V
V _{IH(D)}	High Level dynamic input voltage	2.31	_	_	V
V _{IL(D)}	Low Level dynamic input voltage	_	_	0.99	V

Package Characterisitics

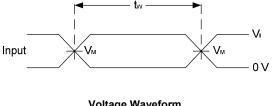
Symbol	Parameter	Test Conditions	Vcc	Min	Тур	Max	Unit
Ci	Input Capacitance	$V_i = V_{CC} - \text{ or GND}$	2.0 to 5.5V	_	3.3	10	pF



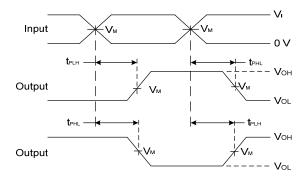
Parameter Measurement Information



V	Inj	outs	.,		
Vcc	VI	t _r / t _f	V _M	CL	
2.0V to 5.5V	V _{CC}	< 3ns	V _{CC} / 2	15pF or 50pF	



Voltage Waveform Pulse Duration



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

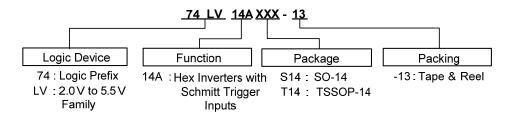
Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate ≤ 10MHz.
- C. Inputs are measured separately one transition per measurement. D. t_{PLH} and t_{PHL} are the same as t_{PD} .

Figure 1 Load Circuit and Voltage Waveforms



Ordering Information



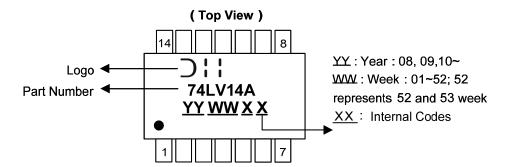
Port Number Backage C		Part Number Package Code Packaging		and Reel
Part Number	Package Code (Note 6)		Quantity	Part Number Suffix
74LV14AS14-13	S14	SO-14	2500/Tape & Reel	-13
74LV14AT14-13	T14	TSSOP-14	2500/Tape & Reel	-13

Note:

6. The taping orientation and tape details can be found at http://www.diodes.com/datasheets/ap02007.pdf

Marking Information

(1) SO14, TSSOP14



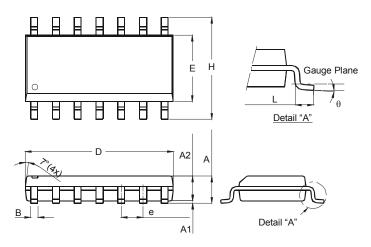
Part Number	Package
74LV14AS14	SO-14
74LV14AT14	TSSOP-14



Package Outline Dimensions (All dimensions in mm.)

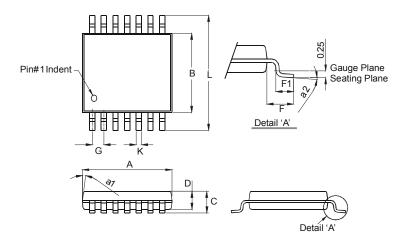
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

Package Type: SO-14



	SO-14	
Dim	Min	Max
Α	1.47	1.73
A 1	0.10	0.25
A2	1.45	Тур
В	0.33	0.51
D	8.53	8.74
E	3.80	3.99
е	1.27	Тур
Н	5.80	6.20
L	0.38	1.27
θ	0°	8°
All Di	mensions	s in mm

Package Type: TSSOP-14



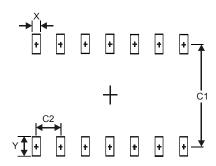
TSSOP-14		
Dim	Min	Max
a1	7° (4X)	
a2	0°	8°
Α	4.9	5.10
В	4.30	4.50
С		1.2
D	0.8	1.05
F	1.00 Typ	
F1	0.45	0.75
G	0.65 Typ	
K	0.19	0.30
L	6.40 Typ	
All Dimensions in mm		



Suggested Pad Layout

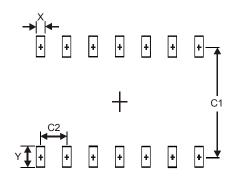
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

Package Type: SO-14



Dimensions	Value (in mm)
Х	0.60
Υ	1.50
C1	5.4
C2	1.27

Package Type: TSSOP-14



Dimensions	Value (in mm)
Х	0.45
Υ	1.45
C1	5.9
C2	0.65



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